

SAMLEX AMERICA, INC.

PHONE (604) 525-3836

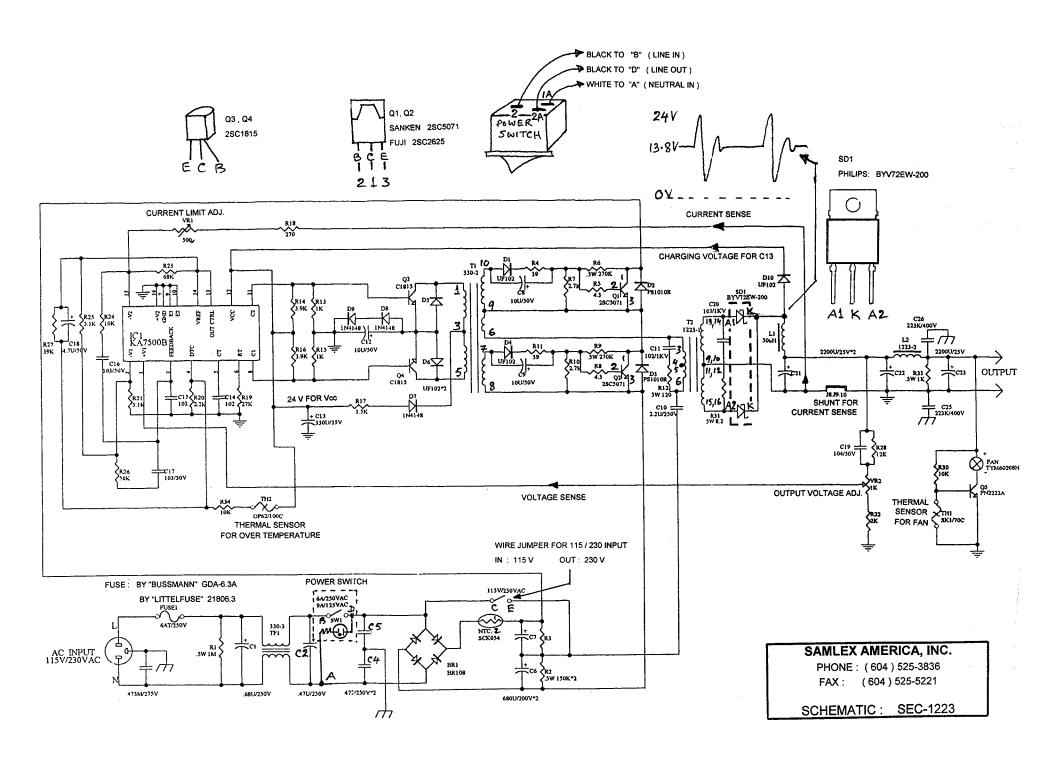
FAX

(604) 525-5221

BILL OF MATERIALS - SEC-1223

DILL OF WATERIALS - GLO-1225								
Parts Name	Specification	Q'ty	Location					
PCB	SEC-1223	1						
	SQM 5% 5W 120R	1	R12					
Resistor	CR 5% 1/2W 1K	1	R33					
Resistor	CR 5% 1/2W 8.2	1	R31					
Resistor	CR 5% 1/2W 150K	2	R2, R3					
Resistor	CR 5% 1.2W 270K	2	R6, R9					
Resistor	CR 5% 1.2W 1M	1	R1					
Resistor	CR 5% 1/4W 4.3	2	R5, R8					
Resistor	CR 5% 1/4W 270	1	R18					
Resistor	39	2	R4, R11					
Resistor	1K	2	R13, R15					
Resistor	1.5K	2	R17, R29					
Resistor	2K	1	R22					
Resistor	2.2K	1	R20					
Resistor	2.7K	2	R7, R10					
Resistor	3.9K	2	R14, R16					
Resistor	5.1 K	2 2 2 3	R21, R25					
Resistor	10K	3	R24, R30, R34					
Resistor	12K	1	R28					
Resistor	27K	1	R19					
Resistor	39K	i	R27					
Resistor	56K	1	R26					
Resistor	68K	1	R23					
1 (00/0101	3311	'	1120					
Jumper Wire	0.8M.M	4 (5)	J1,2,3,4,7					
Jumper Wire	1.0M/M	1	J8					
Jumper Wire	1.2M/M	2	J5, J6					
CGITIPOL TIME			00,00					
Metallized Cap.	(X Cap.) .68uF/250V	1	C1					
Metallized Cap.	(X Cap47uF/250V	1	C2					
Metallized Cap.	225K/250V	1	C10					
Metallized Cap.	223K/400V	2	C25, C26					
Motanizod Oup.	22014 100 \$		020, 020					
Multilayer Cap.	102/50V (NP0)	2	C14, C15					
Multilayer Cap.	103/50V (X7R)	2 2	C16, C17					
Multilayer Cap.	104/50 V (X71V)	2	C19, C24					
manayer cap.	10-700 (200)		010, 024					
Ceramic Cap.	102M/1KV	1	C11					
Ceramic Cap.	103Z/1KV	1	C20					
Ceramic Cap.	(Y Cap.) 222M/400V(AC)	2	AC Socket					
	(Y Cap.) 472M/250V(AC)	1	C4, C5					
Ceramic Cap.	(1 Cap.) 47 ZIVI/200V(AC)		U4, U3					
Electrolytic Con	2200uE/25\/ (46*25\	ာ	C21 C22 C22					
Electrolytic Cap.	2200uF/25V (16*25)	3 1	C21, C22, C23 C13					
Electrolytic Cap.	330uF/35V (10*18)							
Electrolytic Cap.	4.7uF/50V (5*11)	1	C18					
Electrolytic Cap.	10uF/50 V (5*11)	3	C8, C9, C12					

Electrolytic Cap.	600uF/200V (25*35)	2	C6, C7
	·		·
N.T.C	SCK056 / M3R014	1	NTC 2
Diode	HER102	5	D1, 4, 5, 6, 10
Diode	FR107	2	D2, D3
Diode	1 N 4148	3	D7, D8, D9
Diode	BYV72E-200 (Philips)	1	SD1
	(5.1)		
Transistor	2SC2625 (Fuji) / 2SC5071 (Sanken)	2	Q1, Q2
Transistor	2 SC 1815	2	Q3, Q4
Transistor	PN2222A	1	Q5
_	(Carrayan)		_
IC	KA7500B (Samsung)	11	IC1
	or TL494IN (Motorola)		
Variable Resistor	500 Ohm (501)	1	VR1
Variable Resistor	1K (102)	1	VR2
Transformer	1223-1 (ETD-39)	1	T2
Transformer	330-2 (EE-19L)	1	T1
Transformer	330-3 (ET28)	1	TF1
Transformer	23uH	1	<u>L1</u>
Transformer	1223-3 (R6*20)	1	L2
D : 1 D: 1	DD400, 0001//40A	1	DD4
Bridge Diode	BR108 800V / 10A	1 1	BR1
Fuee	/LIL App \ C 2AT/2E0\/ /E*20\	1	FUCE4
Fuse Fuse Holder	(UL App.) 6.3AT/250V (5*20)	2	FUSE1 FUSE1
Fuse Holder Fan	5*20 (7mm) TYM6020BH (12V)	1	Bottom Case
Fall	T FIVIOUZUBH (12 V)		Bollom Case
Spade Terminal (M)	P850	4	L.N.+
Dual Binding Post	WTN-1047	1	Bottom Case
Dual Billuling Fost	VVIII-10-7	<u> </u>	Bottom Gasc
Housing	Upper Cover	1	
Housing	Bottom Cover	1 1	
110001119		'	
Temperature Switch	OP62/100C/080m/m	1	TH-2
Temperature Switch	SK1/070/05/100	1	TH-1
Power Switch	R992KDET2F	1	Bottom Case
Power Switch	R-301 / SS-7B	1	Bottom Case
Power Cord	America 2 sides/0.75/2M	1	Accessory
Wire	1.8*20M/M	3	J8, J9, J10
Rubber Foot	T211308	4	Bottom Case
Rubber Foot	HU-12	2	C4, C5
Heat Sink	P001 (18M/M)		Lock BR1
Heat Sink	L Type 25*96*8 4 Holes	11	Bottom Case
Fixing Metal	73009-A	11	Heat Sink
Rubber Tube	14*25M/M	2	Back of Q1, Q2
Rubber Tube	TO-3P	11	Back of SD1
Cable Tie	YJ-98	2	A.B.D.

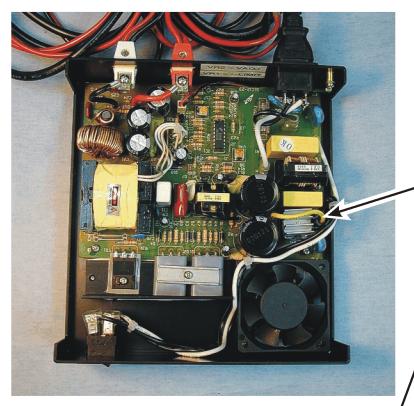


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		C)			nLU -	ULU	

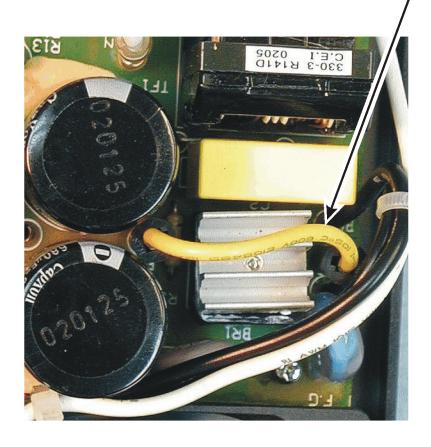
	IERICA, INC. 604) 525-3836	AX	(604) 525-5221
BILL OF N	IATERIALS - SEC-1223		
Parts Name	Specification	Q'ty	Location
P.C.B	SEC12-23	1	- 1341
1.0.5		;	
	SQM 5% 5 W 120R	1	R12
Resistor	CR 5% 1/2W 1K	1	R33
Resistor	CR 5% 1/2W 8.2	1	R31
Resistor	CR 5% 1/2W 150K	2	R2.R3
Resistor	CR 5% 1/2W 270K	2	R6.R9
Resistor	CR 5% 1/2W 1M	1	R1
Resistor	CR 5% 1/4W 4.3	. 2	R5.R8
Resistor	CR 5% 1/4W 270	1	R18
Resistor	39	2	R4.R11
Resistor	1K	2	R13.R15.
Resistor	1.5K	2	R17.29
Resistor	2K	1	R22
Resistor	2.2K	1	R20
Resistor	2.7K	2	R7.R10
Resistor	3.9K	2	R14.R16.
Resistor	5.1K	2	R21.R25
Resistor	10K	3	R24.30.34
Resistor	12K	1	R28
Resistor	27K	1	R19
Resistor	39K	1	R27
Resistor	56K	1	R26
Resistor	68K	1	R23
Jumper Wire	0.8M/M	4	J1.2.3.4.7
Jumper Wire	1.0M/M	: 1	J8
Jumper Wire	1.2M/M	2	J5.6
Metallized Cap.	(X Cap.) .68UF/250V	1	Cl
Metallized Cap.	(X Cap.) .47 UF/250V	1	C2
Metallized Cap.	225K/250V	1	C10
Metallized Cap.	223K/400V	2	C25.C26
Multilayer Cap.	102/50V (NPO)	2	C14.15
Multilayer Cap.	103/50V (X7R)	2	C16.C17
Multilayer Cap.	104/50V (Z5U)	2	C19.24
			· · · · · · · · · · · · · · · · · · ·
Ceramie Cap.	102M/1KV	<u>1</u>	C11
Ceramic Cap.	1037./1KV	1	C20
Ceramic Cap.	(Y Cap.) 222M/400V(AC)	2	AC Socket
Ceramic Cap.	(Y Cap.) 472M/250V(AC)	22	C4.5
		:	
Electrolytic Cap.	2200UF/25V (16*25)	3	C21.22.23
Electrolytic Cap.	330UF/35V (10*18)	<u> </u>	C13
Electrolytic Cap.	4.7UF/50V (5*11)	1	C18
Electrolytic Cap.	10UF/50V (5*11)	: 3	C8.9,12

	<u> </u>		e di kaladysa Mje
Electrolytic Cap.	680UF/200V (25*35)	2	C6.C7
N.T.C	SCK056 / M3R014		NTC 2
1N.1.C.	3CK0307 NISK014		11102
DIODE	HER102	5	D1.4.5.6.10
DIODE	FR107	2	D2.D3
DIODE	IN4148	$-\frac{2}{3}$	D7.8.9
DIODE	BYV72EW-200 (PHILIPS		SD1
DIODE	FUJI - SANKEN	·/	1 301
Transistor	2SC2625 / 2SC5071	2	Q1.Q2
Transistor	2SC1815	2	Q3.Q4
Transistor	PN2222A	1	Q5.Q4
TTAIISISIOI	FNZZZZA		
IC	KA7500B (SAMSUNG	1	IC1
	OR TL494 IN (MOTORO		
Variable Resistor	500 ohm (501)	1	VR1
Variable Resistor		<u>-</u> 1	VR2
- armore regional		-	1
Transformer	1223-1 (ETD-39)	i	T2
Transformer	330-2 (EE-19L)	1	T1
Transformer	330-3 (ET28)	<u>î</u>	TFI
Transformer	23UH	1	L1
Transformer	1223-2 (R6*20)	1	L2
Transformer	. 1223-2 (R0 20)		L
Bridge Diode	BR108 800V, IOA	1	BR1
Druge Diode	DR100 0001, 1071		
Fuse	(UL App.) 6.3AT/250V (5*20	1	FUSE1
Fuse Holder	5*20 (腳距7M/M)	2	FUSE1
Fan	TYM6020BH (12V)	1	Bottom CASE
	:		1
Spade Termina	I (male) P850	4	L.N.+
Dual Binding P		1	Bottom CASE
Housing	Upper COVER	1	
Housing	Bottom CASE	1	
Tionsnig	Bottom Croc		
emperature Switch	OP62/100C/080M/M	1	TH-2
emperature Switch		_1_	TH-1
Power Switch		1	Bottom Case
Power Socket		<u>+</u>	Bottom Case
DWET SUCTO	1001 00 10		Donoin COD C
Power Cord	America 2 sides/0.75/2M	1	Accessory
Wire	1.8*20M/M	^ 3	J8.9.10
TY HU	LO SONEWI		30.7.10
Rubber Foot	T211308	4	Bottom Case
Rubber Tube	HU-12	2	C4.5
Heat Sink	P001 (18M/M)		Lock BR1
Heat Sink	L Type 25*96*8 4 Holes	1	Bottom Case
	73009-A	- <u></u>	Heat Sink
		1	TICAL DUIL
Fixing Metal	and the second of the second o	ີ າ	Ractifof O1 O2
Fixing Metal Rubber Tube	14*25M/M	2	Back of Q1, Q2
Fixing Metal	and the second of the second o	2	Back of Q1, Q2 Back of SD1 A.B.D

SAMLEX SEC-1223 12VDC 23A SWITCHING P/S 120VAC TO 220VAC CONVERSION



FOR 220VAC OPERATION, LIFT ONE END OF THE YELLOW JUMPER RUNNING BETWEEN PINS C & E ON THE PC BOARD.



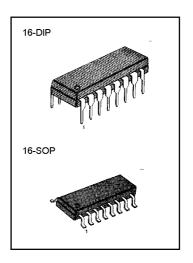


VOLTAGE-MODE PWM CONTROLLER

The KA7500B is used for the control circuit of the pulse width modulation switching regulator. The KA7500B consists of 5V reference voltage circuit, two error amplifiers, flip flop, an output control circuit, a PWM comparator, a dead time comparator and an oscillator. This device can be operated in the switching frequency of 1 KHz to 300 KHz.

FEATURES

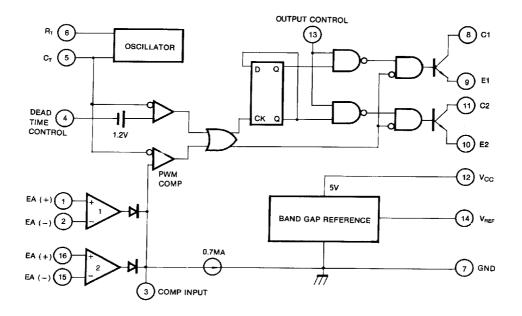
- \bullet Internal regulator provides a stable 5V reference supply trimmed to 1 %
- Uncommitted output TR for 200mA sink or source current
- Output control for push-pull or single-ended operation
- Variable duty cycle by dead time control (pin 4)
 Comlete PWM control circuit
- On-chip oscillator with master or slave operation
- Internal circuit prohibits double pulse at either output



ORDERING INFORMATION

Device	Package	Operating Temperature
KA7500B	16 DIP	0 ~ + 70℃
KA7500BD	16 SOP	0 ~ + 70℃

BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{cc}	42	V
Collector Supply Voltage	Vc	42	V
Output Current	lo	250	mA
Amplifier Input Voltage	V _{IN}	V _{CC} + 0.3	V
Power Dissipation (T _A = 25 ℃)	P _D	1 (KA7500B) 0.9 (KA7500BD)	w
Operating Temperature Range	T _{OPR}	0 ~ +70	°C
Storage Temperature Range	T _{STG}	-65 ~ + 150	$^{\circ}$

ELECTRICAL CHARACTERISTICS

(Vcc = 20V, f = 10KHz, T_A = 0 $^{\circ}\!\mathrm{C}$ $\,$ to + 70 $^{\circ}\!\mathrm{C}$, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
REFERENCE SECTION			•	•		ı
Reference Output Voltage	V _{REF}	I _{REF} = 1mA	4.75	5.0	5.25	V
Line Regulation	ΔV_{REF}	V_{CC} = 7V to 40V		2.0	25	mV
Temperature Coefficient of V _{REF}	$\Delta V_{REF} / \Delta T$	T _A = 0°C to 70°C		0.01	0.03	%/℃
Load Regulation	ΔV_{REF}	I _{REF} = 1mA to 10mA		1.0	15	mV
Short-Circuit Output Currnet	I _{SC}	V _{REF} = 0	10	35	50	mA
OSCILLATOR SECTION						
Oscillation Frequency	f	$C_T = 0.01 \muF$, $R_T = 12 K\Omega$		10		KHz
Frequency Change with Temperature	$\Delta f/\Delta T$	$C_T = 0.01 \muF$, $R_T = 12 K\Omega$			2	%
DEAD TIME CONTROL SECTION			•	•	•	•
Input Bias Currnet	I _{BIAS}	V _{CC} = 15V, 0V < V ₄ < 5.25V		-2.0	-10	μA
Maximum Duty Cycle	D _(MAX)	V _{CC} = 15V, V ₄ = 0V	45			%
maximum 2 asy cycle	- (NO-OX)	O.C Pin = V _{REF}				,,,
Input Threshold Voltage	V _{ITH}	Zero Duty Cycle		3.0	3.3	v
input Tilleshold Voltage	VIIH	Max. Duty Cycle	0			V
ERROR AMP SECTION						
Input Offset Voltage	V _{IO}	$V_3 = 2.5V$		2.0	10	mV
Input Offset Current	I _{IO}	$V_3 = 2.5V$		25	250	mA
Input Bias Current	I _{BIAS}	$V_3 = 2.5V$		0.2	1.0	μΑ
Common Mode Input Voltage	V _{CM}	7V < V _{CC} < 40V	-0.3		V _{cc}	٧
Open-Loop Voltage Gain	G _{VO}	0.5V < V ₃ < 3.5V	70	95		dB
Unit-Gain Bandwidth	BW			650		KHz



ELECTRICAL CHARACTERISTICS

(V_{CC} = 20V, f = 10KHz, T_A = 0 $^\circ\!\mathrm{C}$ to + 70 $^\circ\!\mathrm{C}$, unless otherwise specified)

Characteristic	Symbol	Test Conditions	Min	Тур	Max	Unit
PWM COMPARATOR SECTION						
Input Threshold Voltage	V _{ITH}	Zero Duty Cycle		4	4.5	V
Input Sink Currnet	I _{SINK}	V ₃ =0.7V	-0.3	-0.7		mV
OUTPUT SECTION	•					
Output Saturation Voltage	V _{CE(SAT)}	V _E = 0, I _C = 200mA		1.1	1.3	
Common Emitter						V
Common Collector	V _{CC(SAT)}	$V_C = 15V, I_E = -200mA$		1.5	2.5	
Collector Off-State Currnet	I _{C(OFF)}	V _{CC} = 40V, V _{CE} = 40V		2	100	μA
Emitter Off-State Current	I _{E(OFF)}	$V_{CC} = V_{C} = 40V, V_{E} = 0$			-100	μΑ
TOTAL DEVICE	•		•	•		
Supply Current	Icc	Pin 6 = V _{REF} , V _{CC} = 15V		6	10	mA
OUTPUT SWITCHING CHARACTERI	STIC					
Rise Time	t _R					
Common Emitter				100	200	0
Common Collector				100	200	nS
Fall Time	t _F					
Common Emitter				25	100	0
Common Collector				40	100	nS



TYPICAL APPLICATION

PLUSE WIDTH MODULATED STEP-DOWN CONVERTER

